## NSN 5961-01-066-6357

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**Fiig:** A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-066-6357 **Inclosure Material:** Metal **Overall Length:** 11.0 millimeters **Overall Diameter:** 25.0 millimeters **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-3 **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 1500.0 collector to base voltage/static/emitter open and 1500.0 collector to emitter voltage, dc with base short-circuited to emitter and 5.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 2.50 amperes source cutoff current and 2.50 amperes source cutoff current and 2.50 amperes repetitive peak forward current megahertz **Power Rating Per Characteristic:** 50.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Leads with sleeve; junction pattern arrangement: npn **Terminal Type And Quantity:** 1 case and 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization: No